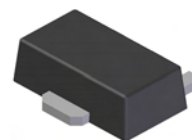


Features

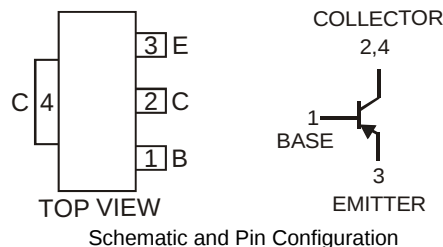
- Epitaxial Planar Die Construction
- Complementary NPN Type Available (2DD1664)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- **Lead Free By Design/RoHS Compliant (Note 1)**
- "Green" Device (Note 2)



SOT89-3L

Mechanical Data

- Case: SOT89-3L
- Case Material: Molded Plastic, "Green" Molding Compound.
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish — Matte Tin annealed over Copper leadframe
(Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.072 grams (approximate)



Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-32	V
Emitter-Base Voltage	V _{EBO}	-5	V
Peak Pulse Current	I _{CM}	-2	A
Continuous Collector Current	I _C	-1	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ T _A = 25°C	P _D	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ T _A = 25°C	R _{θJA}	125	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Conditions
OFF CHARACTERISTICS (Note 4)						
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-40	—	—	V	I _C = -50μA, I _E = 0
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-32	—	—	V	I _C = -1mA, I _B = 0
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5	—	—	V	I _E = -50μA, I _C = 0
Collector Cut-Off Current	I _{CBO}	—	—	-0.5	μA	V _{CB} = -20V, I _E = 0
Emitter Cut-Off Current	I _{EBO}	—	—	-0.5	μA	V _{EB} = -4V, I _C = 0
ON CHARACTERISTICS (Note 4)						
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	-0.125	-0.5	V	I _C = -500mA, I _B = -50mA
DC Current Gain	2DB1132P	82	—	180	—	V _{CE} = -3V, I _C = -100mA
	2DB1132Q	120	—	270	—	
	2DB1132R	180	—	390	—	
SMALL SIGNAL CHARACTERISTICS						
Transition Frequency	f _T	—	190	—	MHz	V _{CE} = -5V, I _E = 50mA f = 30MHz
Output Capacitance	C _{ob}	—	12	30	pF	V _{CB} = -10V, I _E = 0, f = 1MHz

- Notes:
1. No purposefully added lead.
 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 3. Device mounted on FR-4 PCB; pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 4. Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤2%.

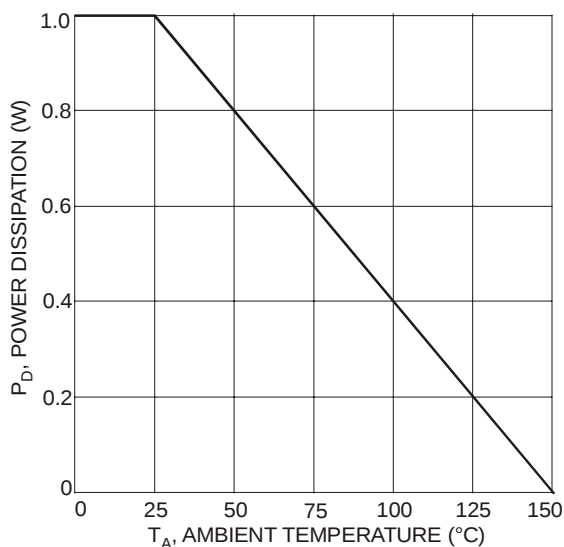


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 3)

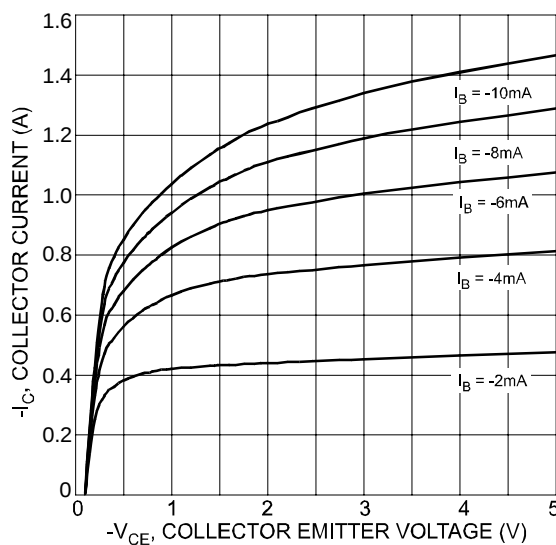


Fig. 2 Typical Collector Current vs. Collector-Emitter Voltage

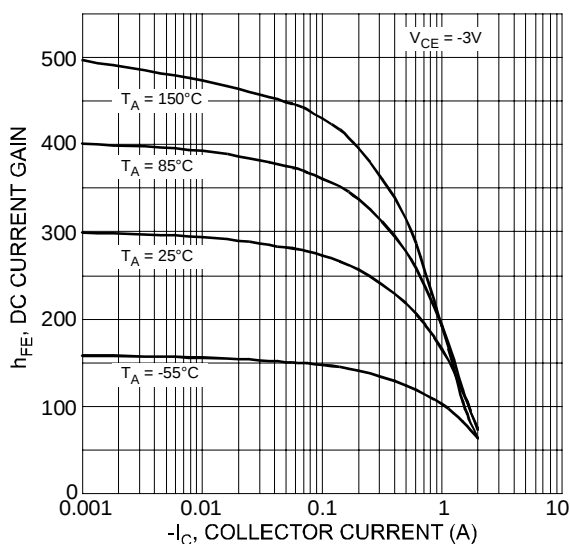


Fig. 3 Typical DC Current Gain vs. Collector Current (2DB1132R)

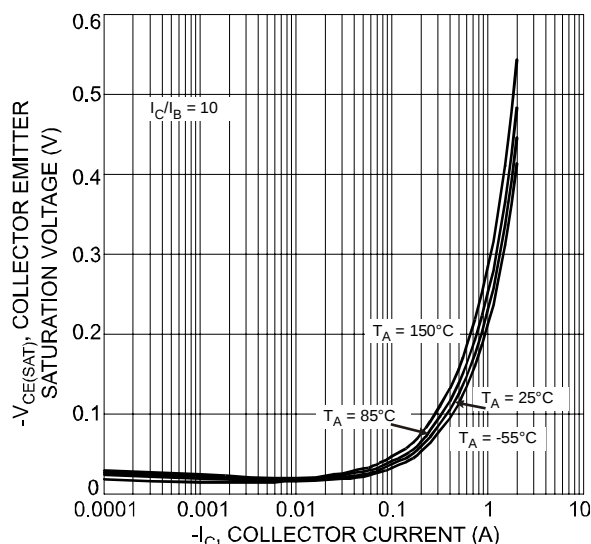


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

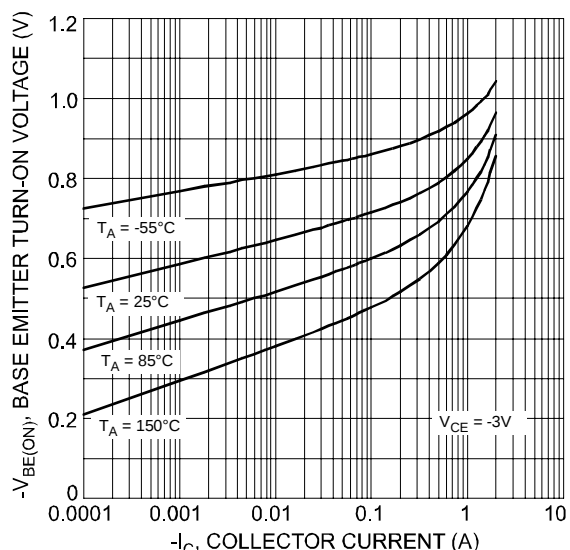


Fig. 5 Typical Base-Emitter Turn-On Voltage vs. Collector Current

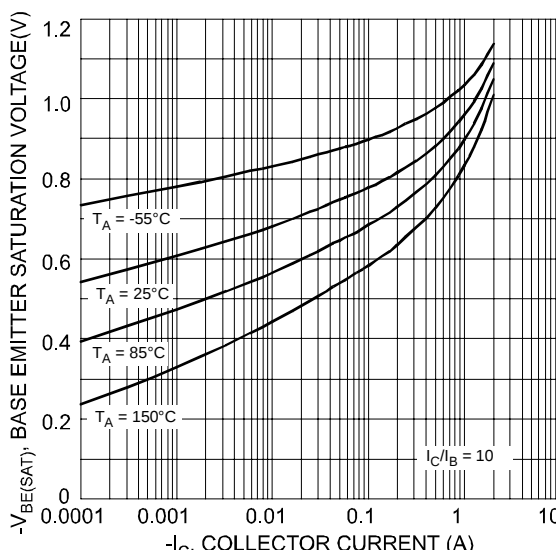
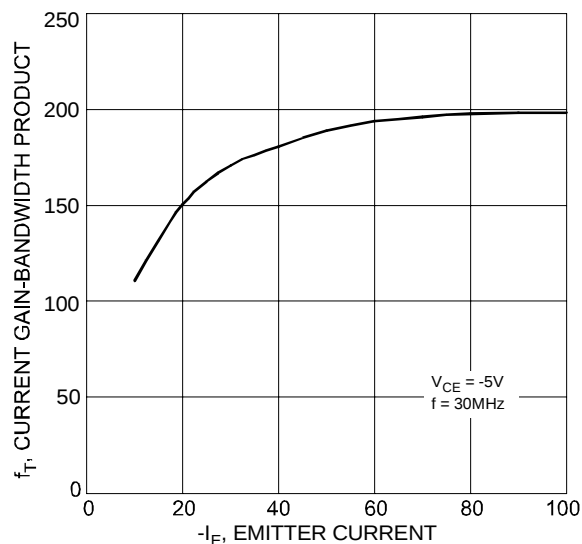
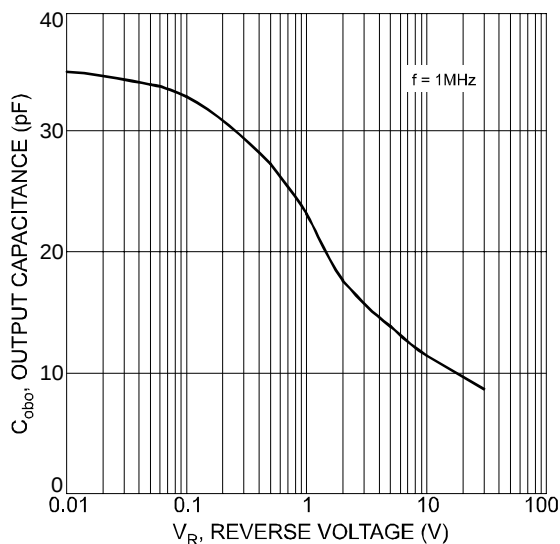


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

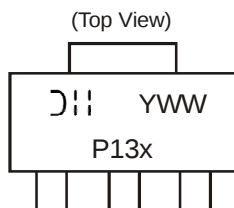


Ordering Information (Note 5)

Device	Packaging	Shipping
2DB1132P-13	SOT89-3L	2500/Tape & Reel
2DB1132Q-13	SOT89-3L	2500/Tape & Reel
2DB1132R-13	SOT89-3L	2500/Tape & Reel

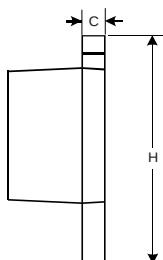
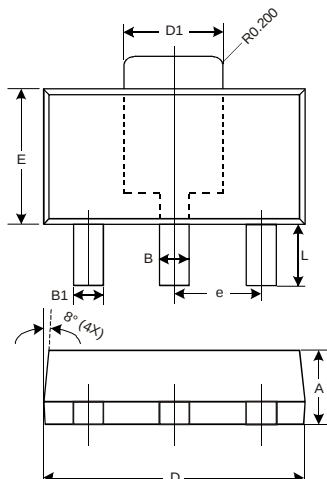
Notes: 5. For packaging details, please see below or go to our website at <http://www.diodes.com/ap02007.pdf>.

Marking Information



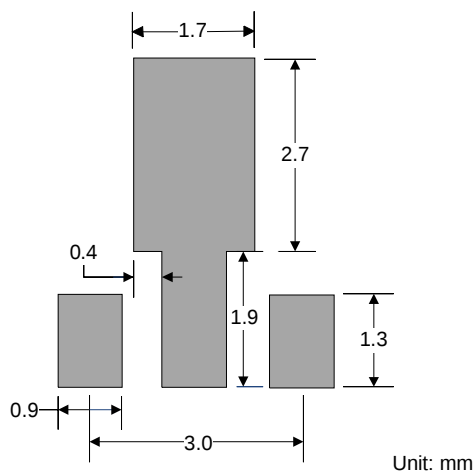
P13x = Product Type Marking Code:
 Where P13P = 2DB1132P
 P13Q = 2DB1132Q
 P13R = 2DB1132R
 YWW = Date Code Marking
 Y = Last digit of year ex: 7 = 2007
 WW = Week code 01 - 52

Package Outline Dimensions



SOT89-3L			
Dim	Min	Max	Typ
A	1.40	1.60	1.50
B	0.45	0.55	0.50
B1	0.37	0.47	0.42
C	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.50	1.70	1.60
E	2.40	2.60	2.50
e	—	—	1.50
H	3.95	4.25	4.10
L	0.90	1.20	1.05
All Dimensions in mm			

Suggested Pad Layout



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